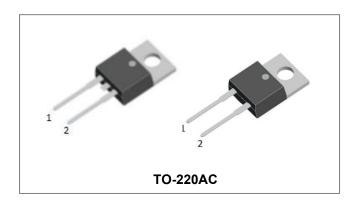






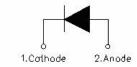
# **MBR1040 SCHOTTKY RECTIFIER**



#### **Features**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- · mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Circuit Diagram**



#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	40	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=140°C	10	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	150	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 10A, Pulse, T <sub>J</sub> = 25 °C	0.57	0.84	V
	$V_{F2}$	@ 10A, Pulse, T <sub>J</sub> = 125 °C	0.52	-	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.008	1.0	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125 °C	8	15	mA
Junction Capacitance	Ст	@ $V_R$ = 5V, $T_C$ = 25 °C $f_{SIG}$ = 1MHz	320	450	pF
Voltage Rate of Change	dv/dt	-	1	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •



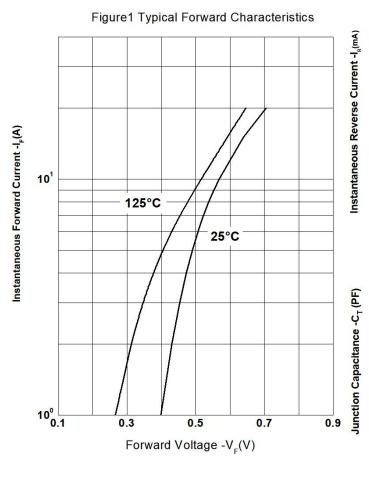


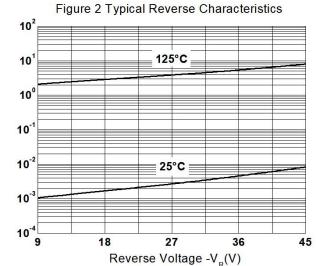


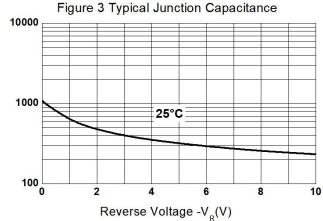
# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> JC	DC operation	1.2	°C/W
Approximate Weight	wt	-	1.6	g
Case Style	TO-220AC			

#### **Ratings and Characteristics Curves**







<sup>•</sup> China - Germany - Korea - Singapore - United States •

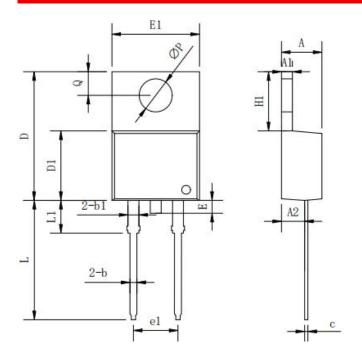
<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •





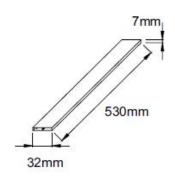


#### **Mechanical Dimensions TO-220AC**

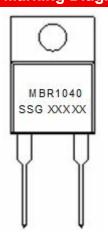


Symbol	Dimensions in millimeters			
	Min. Typical		Max.	
Α	3.56	-	4.83	
A1	0.51	-	1.4	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E	-	-	1.78	
E1	9.65	10.16	10.67	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.7	-	14.73	
L1	-	-	6.35	
ФР	-	3.56	-	
Q	2.54	-	3.43	

## **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type 10 = Forward Current (10A) 40 = Reverse Voltage(40V)

SSG = SSG YY = Year WW = Week L = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

### **Ordering Information**

Device	Package	Shipping	
MBR1040	TO-220AC (Pb-Free)	50 pcs/ tube	

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







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